

1. SGT
2. TOLT BMS
3. $T_j(\text{max}) = 175$
4. MOS EAS

Product Name	Package	Vds V	ID A	V th V typ.	Rds10V mohm typ.	Rds10V mohm max.	Qg10V nC typ.	Tj	N/P
YJTL1D1G08H	TOLT	80	453	3	0.86	1.13	219	-55-175	N
YJTL1D7G10H	TOLT	100	340	2.6	1.28	1.7	166	-55-175	N
YJTL1D9G10H	TOLT	100	270	3	1.5	1.9	132.5	-55-175	N
YJTL2D4G10H	TOLT	100	207	2.9	2	2.4	94	-55-175	N

MOSFET

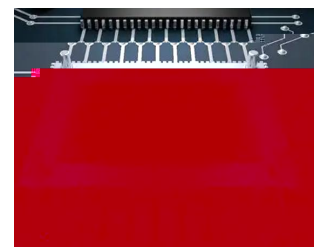
Rdson

MOSFET

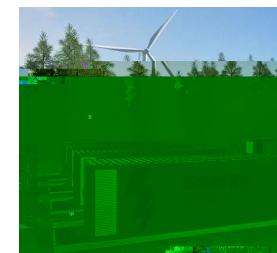
Qg

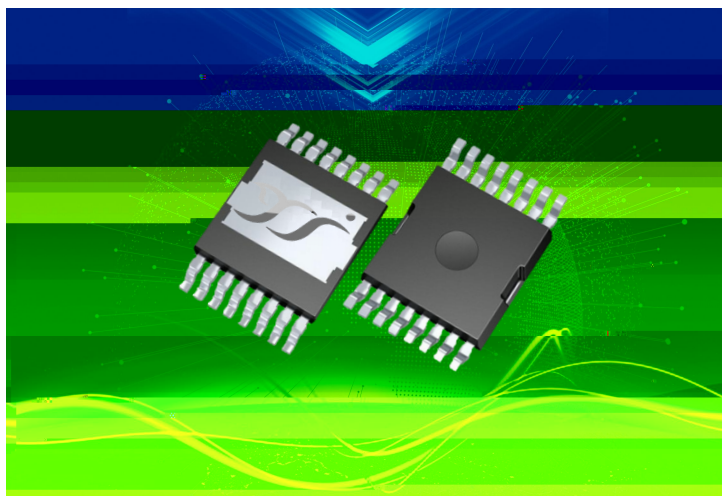
TOLT

SGT



BMS





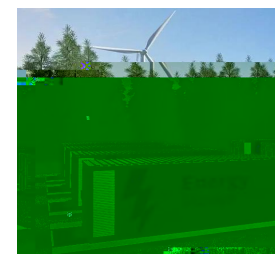
Product Introduction

Product Name	Package	Vds V							

New Product Announcement



BMS



Energy storage